

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-Source Voltage		30	V
V _{GSS}	Gate-Source Voltage		± 20	V
I _D	Drain Current – Continuous	(Note 1a)	7.5	A
	– Pulsed		20	
PD	Power Dissipation for Single Operation	(Note 1a)	1.6	W
		(Note 1b)	1.0	
		(Note 1c)	0.9	
T _J , T _{STG}	Operating and Storage Junction Temperat	ure Range	-55 to +150	°C
Therma	I Characteristics			
Therma R _{0JA}	I Characteristics Thermal Resistance, Junction-to-Ambient	(Note 1a)	78	°C/M

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FDS6910 FDS6910 13"	12mm 25	500 units

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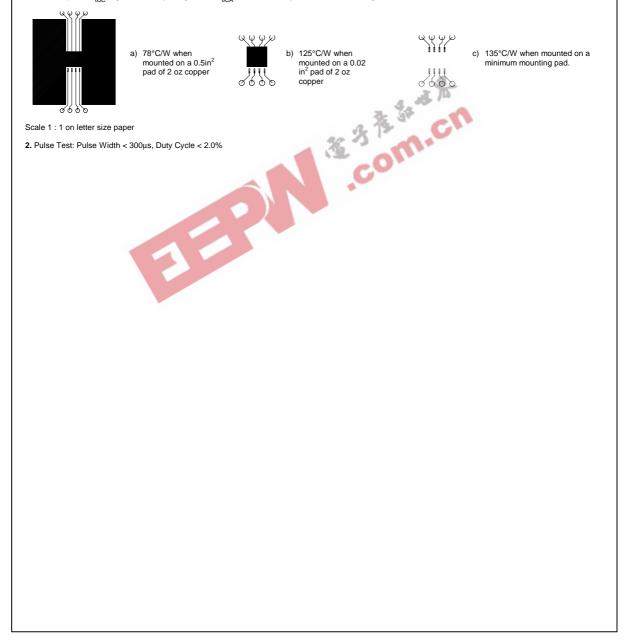


Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 V$, $I_{D} = 250 \mu A$	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		28		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current				1 10	μΑ
I _{GSS}	Gate-Source Leakage	$V_{GS}=\pm 20~V,~V_{DS}=0~V$			±100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1	1.8	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C		-4.7		mV/°C
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS} = 10 \; V, I_D = 7.5 \; A \\ V_{GS} = 4.5 \; V, I_D = 6.5 \; A \\ V_{GS} = 10 \; V, \; I_D = 7.5 \; A, T_J = 125^\circ C \end{array} $		10.6 13 14.5	13 17 20	mΩ
I _{D(on)}	On–State Drain Current	V _{GS} = 10 V, V _{DS} = 5 V	20			А
g _{FS}	Forward Transconductance	$V_{DS} = 5 V$, $I_D = 7.5 A$	1	36		S
Dynamic	Characteristics	34 St	2			
Ciss	Input Capacitance	$V_{DS} = 15 V$, $V_{GS} = 0 V$,	1	1130		pF
Coss	Output Capacitance	f = 1.0 MHz		300		pF
C _{rss}	Reverse Transfer Capacitance	CO.		100		pF
R _G	Gate Resistance	V _{GS} = 15 mV, f = 1.0 MHz		2.4		Ω
Switchin	g Characteristics (Note 2)		•	•		
t _{d(on)}	Turn–On Delay Time	$V_{DD} = 15 V, I_D = 1 A,$		9	18	ns
t _r	Turn-On Rise Time	$V_{GS} = 10 \text{ V}, R_{GEN} = 6 \Omega$		5	10	ns
t _{d(off)}	Turn-Off Delay Time			26	42	ns
t _f	Turn-Off Fall Time			7	14	ns
Q _{g(TOT)}	Total Gate Charge at Vgs=10V			17	24	nC
Qg	Total Gate Charge at Vgs=5V	$V_{DD} = 15 V$, $I_D = 7.5 A$,		9	13	nC
Q _{gs}	Gate-Source Charge			3.1		nC
Q _{qd}	Gate-Drain Charge	1		2.7	1	nC

	Electrical Characteristics TA = 25°C unless otherwise noted						
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Drain-Sc	ource Diode Characteristics an	nd Maximum Ratings					
ls	Maximum Continuous Drain–Source	Diode Forward Current			1.3	А	
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = 1.3 A$ (Note 2)			1.2	V	
			1			•	
t _{rr}	Diode Reverse Recovery Time	$I_F = 7.5 \text{ A}, d_{iF}/d_t = 100 \text{ A}/\mu \text{s}$		24		nS	

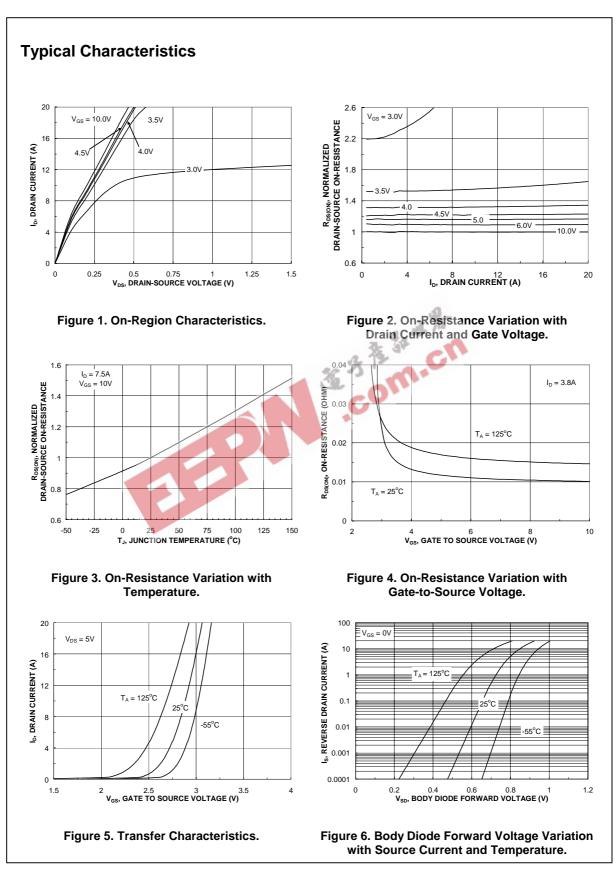
Notes:

1. R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design while R_{0CA} is determined by the user's board design.



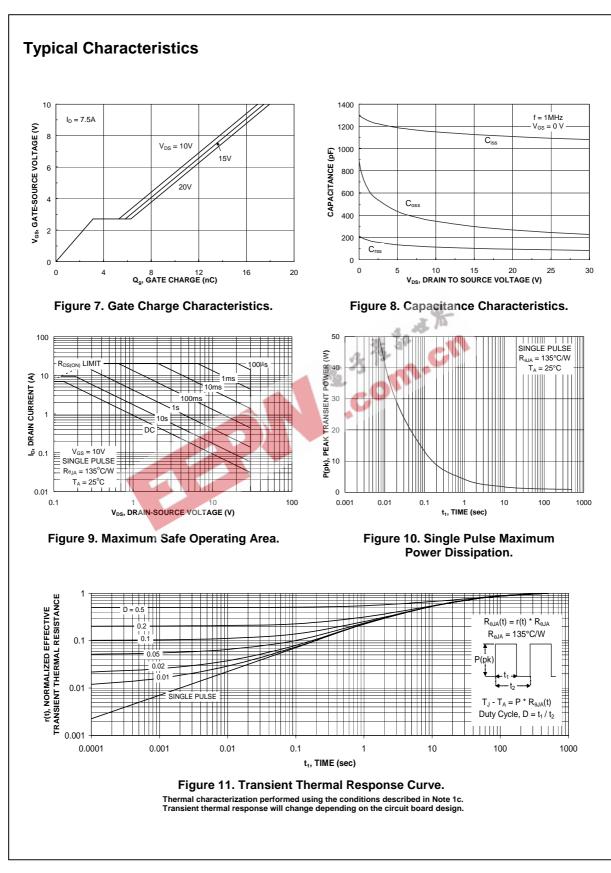
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